#### Nch 650V 11A Power MOSFET

V <sub>DSS</sub>	650V
R <sub>DS(on)</sub> (Max.)	0.4Ω
I <sub>D</sub>	±11A
P <sub>D</sub>	124W

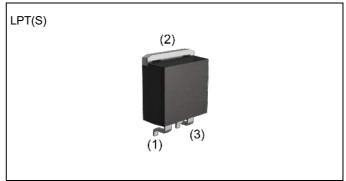
Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Parallel use is easy
- 4) Pb-free plating; RoHS compliant

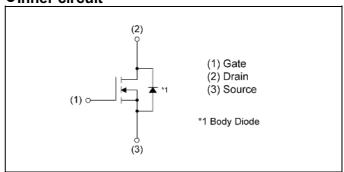
## Application

Switching

#### Outline



#### •Inner circuit



Packaging specifications

Packing	Embossed Tape
Packing code	TL
Marking	R6511ENJ
Basic ordering unit (pcs)	1000

## ullet Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V <sub>DSS</sub>	650	V
Continuous drain current (T <sub>c</sub> = 25°C)		I <sub>D</sub> *1	±11	Α
Pulsed drain current		I <sub>DP</sub> *2	±33	А
Coto Course vallesse	static	V	±20	V
Gate - Source voltage	AC(f>1Hz)	V <sub>GSS</sub>	±30	V
Avalanche current, single pulse		I <sub>AS</sub>	1.8	А
Avalanche energy, single pulse		E <sub>AS</sub> *3	223	mJ
Power dissipation (T <sub>c</sub> = 25°C)	P <sub>D</sub>	124	W	
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and storage tempera	ature range	T <sub>stg</sub>	-55 to +150	°C

#### ●Thermal resistance

Davamatav	Cymah al	Values			1.1
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *4	-	-	1.0	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *5	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Cumb al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		650	-	-	V
		$V_{DS} = 650V, V_{GS} = 0V$				
Zero gate voltage drain current	I <sub>DSS</sub>	$T_j = 25^{\circ}C$	-	-	100	μΑ
		$T_j = 125^{\circ}C$	-	-	1000	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	-	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 320 \mu A$	2	-	4	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.8A				
Static drain - source on - state resistance	R <sub>DS(on)</sub> *6	$T_j = 25^{\circ}C$	-	0.36	0.4	Ω
		$T_j = 125^{\circ}C$	-	-	-	
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	7.7	-	Ω

### ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatar	Cymah al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	670	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	780	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	85	-	
Turn - on delay time	t <sub>d(on)</sub> *6	$V_{DD} \simeq 300V$ , $V_{GS} = 10V$	-	25	-	
Rise time	t <sub>r</sub> *6	I <sub>D</sub> = 5.5A	-	35	-	
Turn - off delay time	t <sub>d(off)</sub> *6	$R_L \simeq 54.9\Omega$	-	90	-	ns
Fall time	t <sub>f</sub> *6	$R_G = 10\Omega$	-	30	-	

### ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Darameter	Cymabal	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*6}$	V <sub>DD</sub> ≈ 300V	-	32	-	
Gate - Source charge	Q <sub>gs</sub> *6	I <sub>D</sub> = 11A	-	5.5	-	nC
Gate - Drain charge	Q <sub>gd</sub> *6	V <sub>GS</sub> = 10V	-	14	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> ≈ 300V, I <sub>D</sub> = 11A	-	6.0	-	V

<sup>\*1</sup> Limited only by maximum channel temperature allowed.

<sup>\*2</sup> Pw ≤ 10µs, Duty cycle ≤ 1%

<sup>\*3</sup> L $\doteqdot$ 100mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>i</sub>=25 $^{\circ}$ C

<sup>\*4</sup> T<sub>C</sub>=25°C

<sup>\*5</sup> Mounted on an epoxy PCB FR4 (25mm x 27mm x 0.8mm)

<sup>\*6</sup> Pulsed

### ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Source current	I <sub>S</sub> *1	T <sub>C</sub> = 25°C	1	-	11	Α
Pulsed source current	l <sub>SP</sub> *2	1C - 23 C	1	-	33	Α
Source-Drain voltage	V <sub>SD</sub> *6	$V_{GS} = 0V, I_{S} = 11A$	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *6		-	430	-	ns
Reverse recovery charge	Q <sub>rr</sub> *6	I <sub>S</sub> = 11Α di/dt = 100Α/μs	-	4.9	-	μC
Peak reverse recovery current	I <sub>rr</sub> *6		-	23	-	А

Fig.1 Power Dissipation Derating Curve

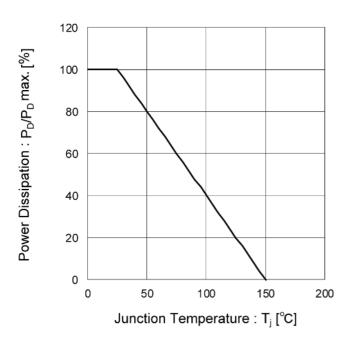


Fig.2 Drain Current Derating Curve

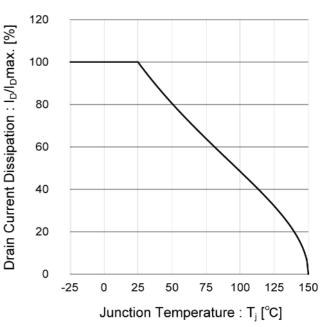


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

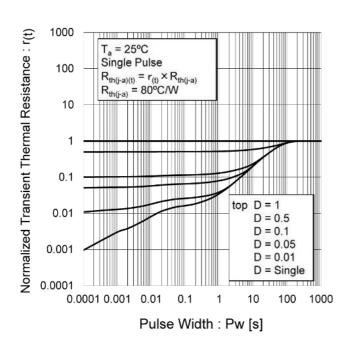


Fig.4 Maximum Safe Operating Area

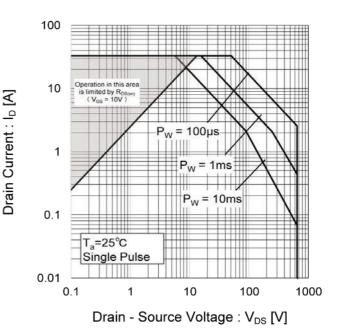


Fig.5 Avalanche Energy Derating Curve

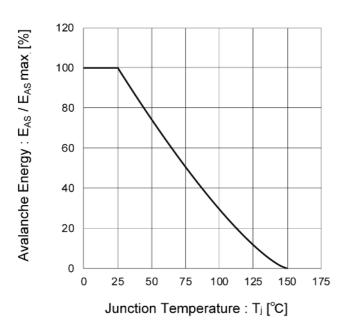


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

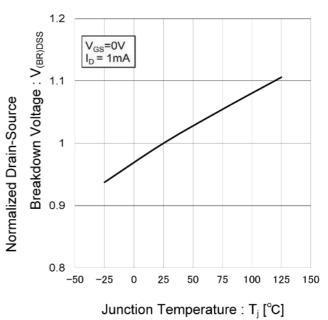


Fig.7 Typical Output Characteristics(I)

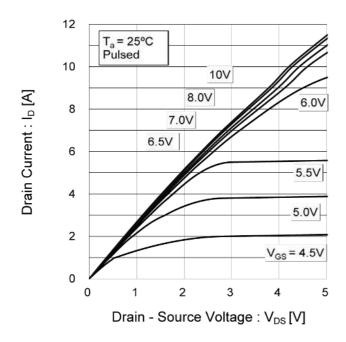
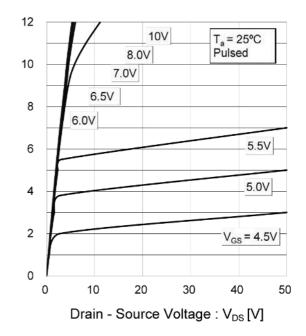


Fig.8 Typical Output Characteristics(II)



Drain Current: Ip [A]

Fig.9 Typical Transfer Characteristics

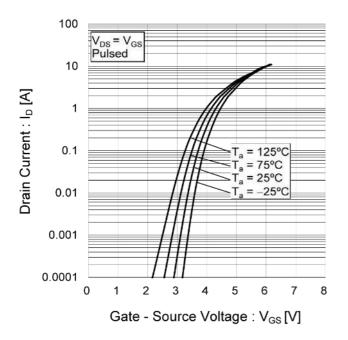


Fig.10 Normalized Gate Threshold

Voltage vs. Junction Temperature

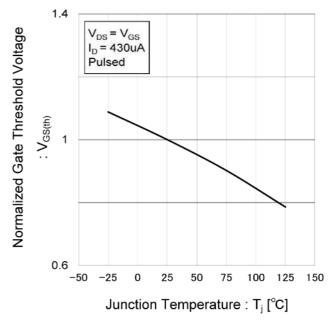


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

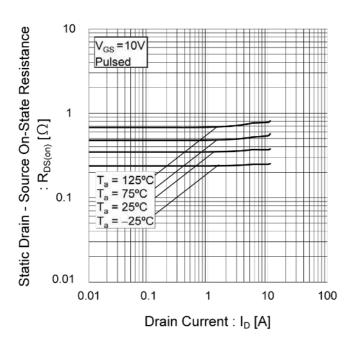


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

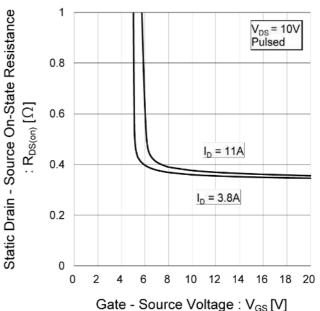


Fig.13 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature

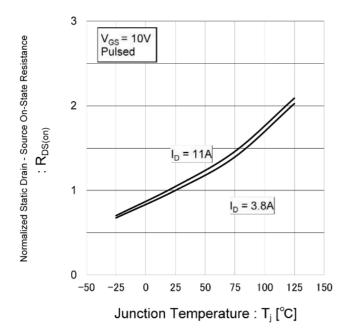


Fig.14 Typical Capacitance vs.
Drain - Source Voltage

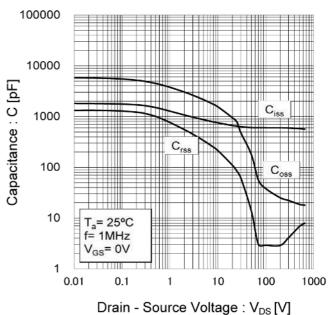


Fig.15 Switching Characteristics

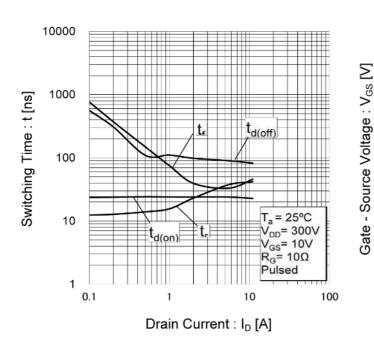


Fig.16 Typical Gate Charge

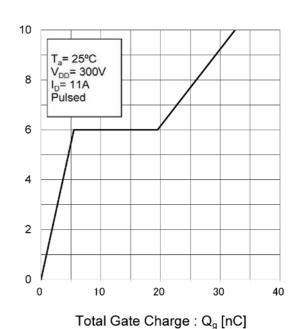


Fig.17 Source Current vs. Source - Drain Voltage

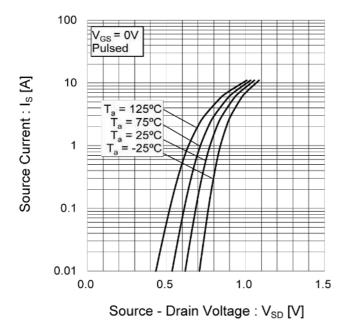
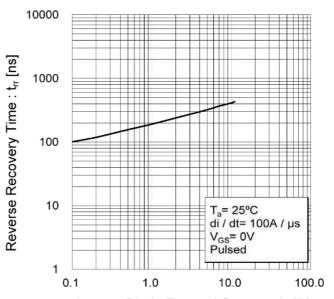


Fig.18 Reverse Recovery Time vs.
Inverse Diode Forward Current



#### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

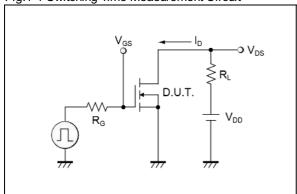


Fig.2-1 Gate Charge Measurement Circuit

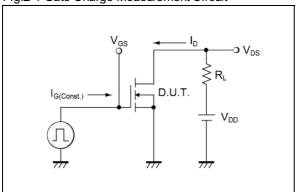


Fig.3-1 Avalanche Measurement Circuit

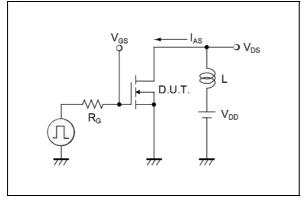


Fig.4-1 trr Measurement Circuit

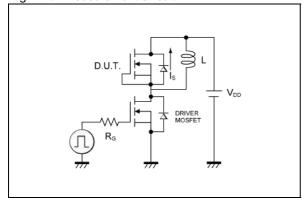


Fig.1-2 Switching Waveforms

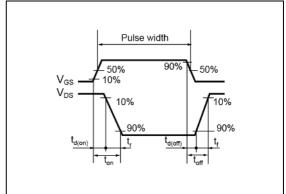


Fig.2-2 Gate Charge Waveform

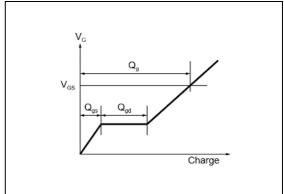


Fig.3-2 Avalanche Waveform

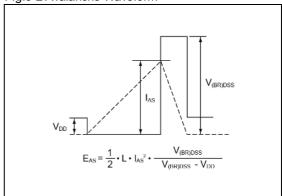
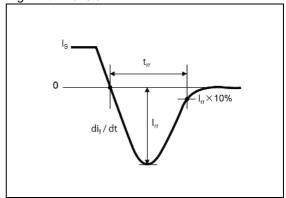
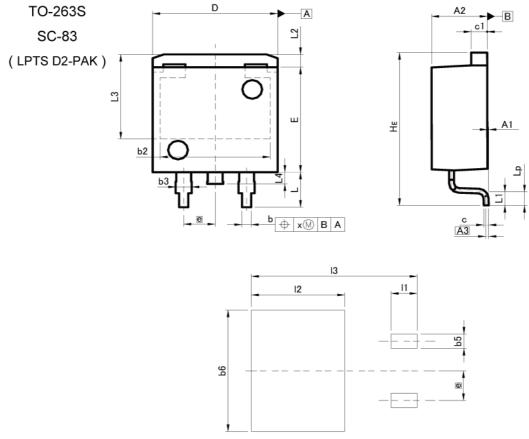


Fig.4-2 trr Waveform



### Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.30	0.000	0.012	
A2	4.30	4.70	0.169	0.185	
A3	0.	25	0.0	10	
b	0.68	0.98	0.027	0.039	
b2	8.	90	0.3	350	
b3	1.14	1.44	0.045	0.057	
С	0.30	0.60	0.012	0.024	
c1	1.10	1.50	0.043	0.059	
D	9.80	10.40	0.386	0.409	
E	8.80	9.20	0.346	0.362	
е	2.	54	0.100		
HE	12.80	13.40	0.504	0.528	
L	2.70	3.30	0.106	0.130	
L1	1.	20	0.0	147	
L2	1.	10	0.0	143	
L3	7.	25	0.285		
L4		00	0.039		
Lp	0.90	1.50	0.035	0.059	
Х		0.25	177	0.010	
5.11	MILIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
b5	= (	1.23	-	0.049	
b6	<del>=</del> 0	10.40	5 <del>-4</del>	0.409	
П	226	2.10	<u> 1924</u>	0.083	
12	<del>45</del> 8	7.55	1177	0.297	
13		13.40	) <del></del>	0.528	

Dimension in mm/inches



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CLASSIV	CLASSⅢ	CLASSⅢ	CLASSIII

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  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
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  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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